



IFW

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Yi Ding
Assignee: ProMOS Technologies, Inc.
Title: Nonvolatile Memory Cell With Multiple Floating Gates Formed After the Select Gate
Application No.: 10/631,941 Filing Date: July 30, 2003
Examiner: Unknown Group Art Unit: 2812
Docket No.: M-15171 US

San Jose, California
November 3, 2004

Mail Stop Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT UNDER 37 CFR § 1.97(b)

Dear Sir:

Pursuant to 37 CFR § 1.56, § 1.97 and § 1.98, the documents listed on the accompanying form PTO-1449 are called to the attention of the Examiner for the above patent application. Copies of these documents are enclosed except for United States Patents and United States Published Patent Applications.

Citation of these documents shall not be construed as:

1. an admission that the documents are necessarily prior art with respect to the instant invention;
2. a representation that a search has been made, other than as described above; or
3. an admission that the information cited herein is, or is considered to be material to patentability as defined in § 1.56(b).

No fee is believed to be required. If a fee is required for this Information Disclosure Statement, please charge the fee to Deposit Account No. 50-2257. This paper is being submitted in duplicate.

I hereby certify that this correspondence is being deposited with the United States Postal Service as First Class Mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on November 3, 2004.

Michael Shenker 11-3-04
Attorney for Applicant Date of Signature

Respectfully submitted,

Michael Shenker
Michael Shenker
Attorney for Applicant(s)
Reg. No. 34,250

LAW OFFICES OF
MacPherson, Kwok, Chen &
Heid LLP
1762 Technology Drive, Suite 226
San Jose, CA 95110
Telephone (408) 392-9520
Fax (408) 392-9262

U.S. Department of Commerce, Patent and Trademark Office		Atty Docket No.	Serial No.
		M-15171 US	10/631,941
INFORMATION DISCLOSURE STATEMENT BY APPLICANT		Applicant	
(Use several sheets if necessary)		Yi Ding	
		Filing Date	Group
		July 30, 2003	2812

U.S. Patent Documents

*Examiner Initial		Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate
	AA	6,265,739	Jul. 2001	Yaegashi et al.			
	AB	6,747,310	Jun. 2004	Fan et al.			
	AC	2003/0205776	Nov. 2003	Yaegashi et al.			
	AD	6,468,865	Oct. 2002	Yang et al.			
	AE	6,218,689	Apr. 2001	Chang et al.			
	AF	6,214,669	Apr. 2001	Hisamune			
	AG	6,162,682	Dec. 2000	Kleine			
	AH	6,232,185	May-01	Wang			
	AI	5,912,843	Jun. 1999	Jeng			
	AJ	6,436,764	Aug. 2002	Hsieh			
	AK	6,344,993	5 Feb. 2002	Harari et al.			
	AL	5,668,757	Sept. 1997	Jeng			
	AM	6,355,524	Mar. 2002	Tuan et al.			
	AN	6,696,340	Feb. 2004	Furuhata			
	AQ	5,705,415	Jan. 1998	Orlowski et al.			
	AP						
	AQ						
	AR						
	AS						
	AT						
	AU						
	AV						
	AW						
	AX						
	AY						
	AZ						

Examiner

Date Considered

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with your communication to applicant.